

Vacuum Systems Lecture 4

V. Baglin

CERN TE-VSC, Geneva



Outline

- 1. Synchrotron radiation and photodesorption
- 2. Vacuum instability and ion stimulated desorption
 - 3. Particle losses and ion stimulated desorption
 - 4. Electron cloud and related surface parameters

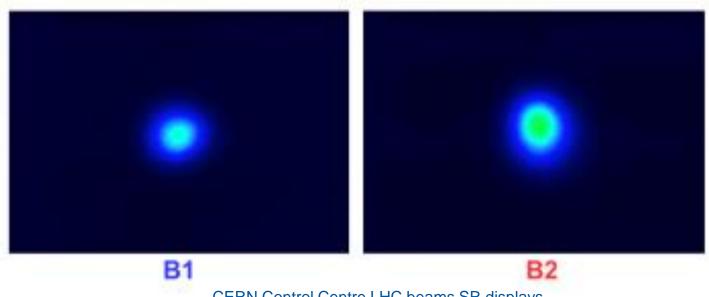
Synchrotron radiation and photodesorption

1.1 Synchrotron radiation

Synchrotron radiation: visible light

- In synchrotron, particles can radiate light by synchrotron radiation
- Can be used for diagnostics purposes :

LHC SYNCHROTRON LIGHT MONITORS



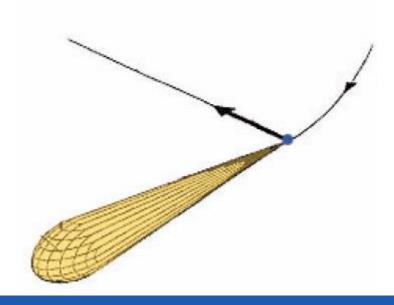
- CERN Control Centre LHC beams SR displays
- But particles loose energy by synchrotron radiation → should be compensated by RF system
- Beam emittance shrink by synchrotron radiation
- Power is dissipated on the machine elements
- Molecules are desorbed from the vacuum chamber wall due to synchrotron radiation

Synchrotron Radiation

- A charged particle which is accelerated produce radiation
- The power of the centripetal radiation is larger than the longitudinal radiation (factor γ^3)
- For a relativistic particle, the radiation is highly peaked (opening angle $\sim 1/\gamma$)
- The radiation energy range from infra-red to gamma rays: from meV to MeV

References:

K. Hübner, CAS 1984, CERN 85-19R.P. Walker, CAS 1992, CERN 94-01A. Hofmann, CAS 1996, CERN 98-04L. Rivkin, CAS 2008



Critical energy

The critical energy split the <u>power spectrum</u> in two equals parts

$$\varepsilon_c = \frac{3}{2} \frac{\text{hc}}{2\pi} \frac{\gamma^3}{\rho}$$

Electrons :
$$\varepsilon_c[eV] = 2.21810^3 \frac{E[GeV]^3}{\rho[m]}$$

Protons:
$$\varepsilon_c[eV] = 3.5835 \, 10^{-7} \, \frac{E[GeV]^3}{\rho[m]}$$

- 90 % of the emitted photons have an energy lower than the critical energy
- Magnetic rigidity:

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B
$$\rho = \frac{p}{e} \approx \frac{E}{e c}$$
 $\frac{1}{\rho} \approx \frac{3}{10} \frac{B[T]}{E[GeV]}$ $\varepsilon_c \propto \frac{E^3}{\rho} \propto B E^2$

$$\varepsilon_c \propto \frac{\mathrm{E}^3}{
ho} \propto \mathrm{B}\,\mathrm{E}^2$$

Dissipated power

The energy emitted by the synchrotron radiation per turn and per particle is:

$$\Delta E = \frac{e^2}{3\varepsilon_0} \frac{\gamma^4}{\rho} = \frac{4\pi}{3} r \,\mathrm{m_0 c^2} \frac{\gamma^4}{\rho}$$

with
$$r = \frac{1}{4\pi\epsilon_0} \frac{e^2}{m_0 c^2}$$
 (classical radius)

The average power emitted per turn by the beam is:

$$P_{\text{tour}} = \Delta E \frac{N}{t} = \frac{e \gamma^4}{3\pi \varepsilon_0 \rho} I$$

So, the average power emitted by the beam per unit of length is:

$$P_0 = \frac{\partial P}{\partial s} = \frac{e \gamma^4}{6\pi \varepsilon_0 \rho^2} I$$

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$$P_0 \propto \frac{E^4}{\rho^2} I \propto B^2 E^2 I$$

Dissipated power

• The average power emitted by the beam per unit of length is

$$P_{0} [W/m] = \frac{e}{3\varepsilon_{0} (m_{0}c^{2})^{4}} \frac{E^{4}}{2\pi\rho^{2}} I \qquad P_{0} \propto \frac{E^{4}}{\rho^{2}} I \propto B^{2}E^{2}I$$

$$P_0 \propto \frac{E^4}{\rho^2} I \propto B^2 E^2 I$$

- Electrons:
 - $P_0 [W/m] = 88.57 \frac{E[GeV]^4}{2\pi \rho [m]^2} I[mA]$
- Protons:

$$P_0 [W/m] = 7.79 \, 10^{-12} \, \frac{E[GeV]^4}{2\pi \, \rho[m]^2} I[mA]$$

Power spectrum

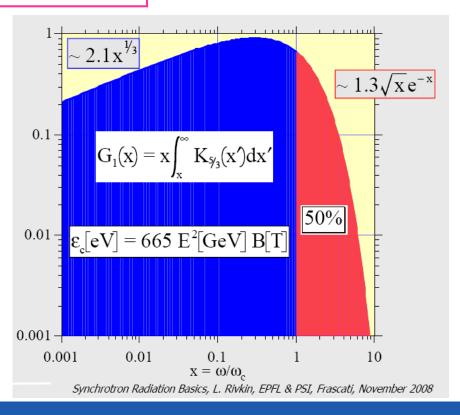
• The SR power emitted by a particle is a function of the vertical angle and the wavelength.

Integrating over the vertical angle, one obtains the spectral power density per unit of

length:

$$\frac{\partial^2 \mathbf{P}}{\partial \mathbf{s} \partial \varepsilon} = \mathbf{P}_0 \frac{1}{\varepsilon_c} \mathbf{S} \left(\frac{\varepsilon}{\varepsilon_c} \right)$$

with
$$S(x) = \frac{9\sqrt{3}}{8\pi} x \int_{x}^{\infty} K_{\frac{5}{3}}(z) dz$$
 ("universal function")



Photon flux

- Since the photon flux is linked to the power by : $P = \Gamma \varepsilon$
- The photon flux per unit length in a relative energy band is written:

$$\frac{\partial \Gamma}{\partial \varepsilon / \varepsilon} = \frac{\partial^2 P}{\partial s \partial \varepsilon} = P_0 \frac{1}{\varepsilon_c} S \left(\frac{\varepsilon}{\varepsilon_c} \right)$$

So, the total photon flux per unit of length is:

$$\dot{\Gamma} = \int_0^\infty \frac{\partial \dot{\Gamma}}{\partial \varepsilon} d\varepsilon = \frac{P_0}{\varepsilon_c} \times \int_0^\infty \left(\frac{\varepsilon}{\varepsilon_c}\right)^{-1} S\left(\frac{\varepsilon}{\varepsilon_c}\right) d\left(\frac{\varepsilon}{\varepsilon_c}\right) = \frac{15\sqrt{3}}{8} \frac{P_0}{\varepsilon_c} = \frac{5\sqrt{3}e}{12 h \varepsilon_0 c} \frac{\gamma}{\rho} I$$

$$\Gamma \propto \frac{E}{\rho} I \propto B I$$

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Linear photon flux

• The photon flux per unit of length is given by :

$$\dot{\Gamma} = \frac{15\sqrt{3}}{8} \frac{P_0}{\varepsilon_c} = \frac{5\sqrt{3}e}{12 h \varepsilon_0 c} \frac{\gamma}{\rho} I \qquad \dot{\Gamma} \propto \frac{E}{\rho} I \propto B I$$

$$\overset{\bullet}{\Gamma} \propto \frac{\mathrm{E}}{\rho} \mathrm{I} \propto \mathrm{B} \, \mathrm{I}$$

Electrons:

$$\Gamma[\text{photons.m}^{-1}.\text{s}^{-1}] = 1.28810^{17} \frac{\text{E[GeV]}}{\rho[\text{m}]} \text{I[mA]}$$

Protons:

$$\Gamma[\text{photons.m}^{-1}.\text{s}^{-1}] = 7.01710^{13} \frac{\text{E[GeV]}}{\rho[\text{m}]} \text{I[mA]}$$

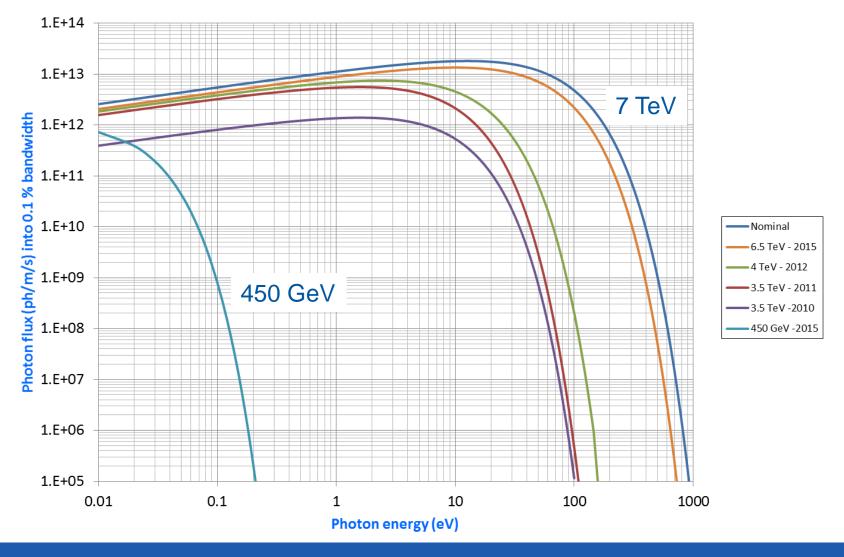
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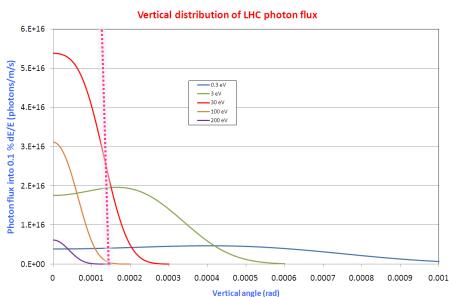
LHC SR Spectrum: from IR to UV

- With nominal parameters: 7 TeV and 585 mA
- 2010, 2011, 2012 and 2015 spectra

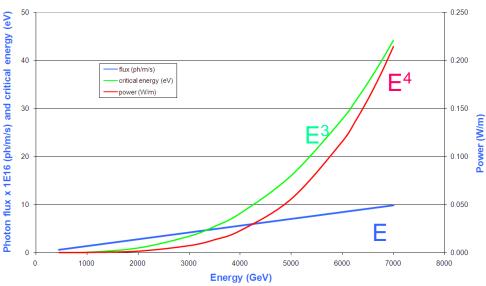
Key parameter: photodesorption yield



LHC SR properties

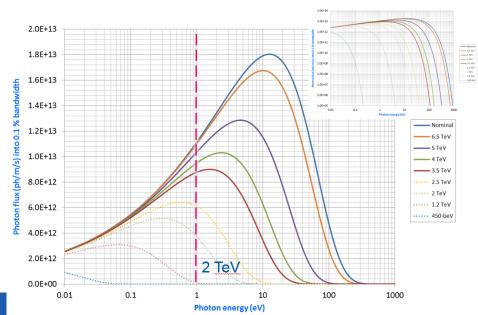


LHC synchrotron radiation at 560 mA



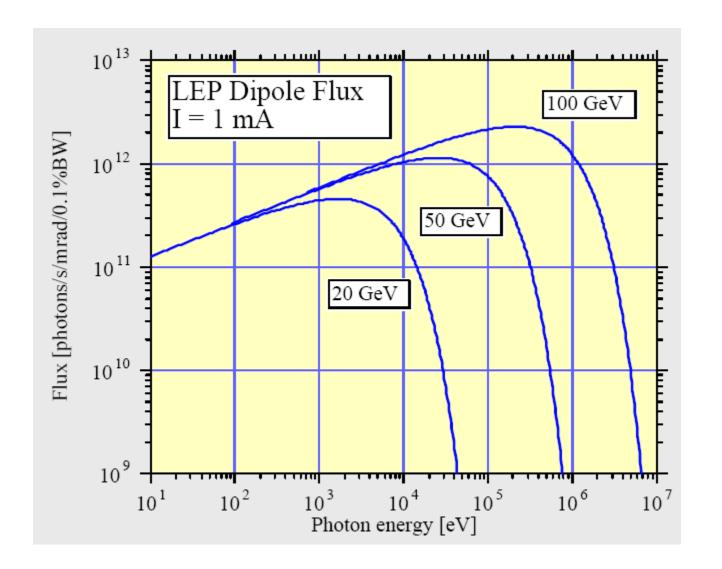
1/gamma opening angle

7 TeV $\epsilon_c = 44 \text{ eV}$ 0.2 W/m $10^{17} \text{ photons/m/s}$ 1/gamma = 0.13 mrad





LEP SR spectrum: X-rays & gamma rays



SR impact on different type of machines ...

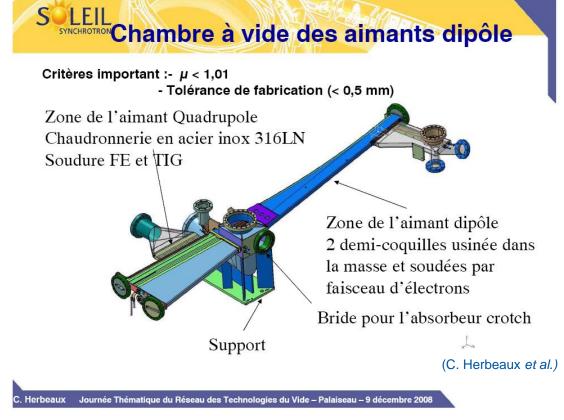
		Soleil	KEK-B		LEP			LHC	
			LER	HER	lnj.	1	2	lnj.	Col.
Particle		e-	e+	e-	e-	e-	e⁻	р	р
Beam current	mA	500	2600	1100	3	3	7	584	584
Energy	GeV	2.75	3.5	8	20	50	96	450	7000
Bending radius	m	5.36	16.31	104.46	2962.96 2784.302			1.302	
Power	W/m	4 030	20 675	5 820	0.8	30	955	0	0.2
Critical energy	eV	8 600	5 800	11 000	6 000	94 000	660 000	0	44
Photon flux	photons/m/s	3 10 ¹⁹	7 1019	1 10 ¹⁹	3 1015	7 10 ¹⁵	3 10 ¹⁶	7 10 ¹⁵	1 1017
Dose at 3000 h	photons/m	4 10 ²⁶	8 10 ²⁶	1 10 ²⁶	3 10 ²²	7 10 ²²	3 10 ²³	7 10 ²²	1 10 ²⁴

- In LEP, and all synchrotron light sources, the evacuation of the power is an issue
- The LHC operates at 7 TeV with ~ .6 A. Power evacuation is an issue for the cryogenic system (1 kW/arc !!)
- The critical energy varies from a few 10 eV to 660 keV. Strongly bound molecules can be desorbed
- The photon flux is large, so large gas load. Adequate dimensioning of the effective pumping speed is required
- The annual photon dose is large. Implications on gas reduction and radiation



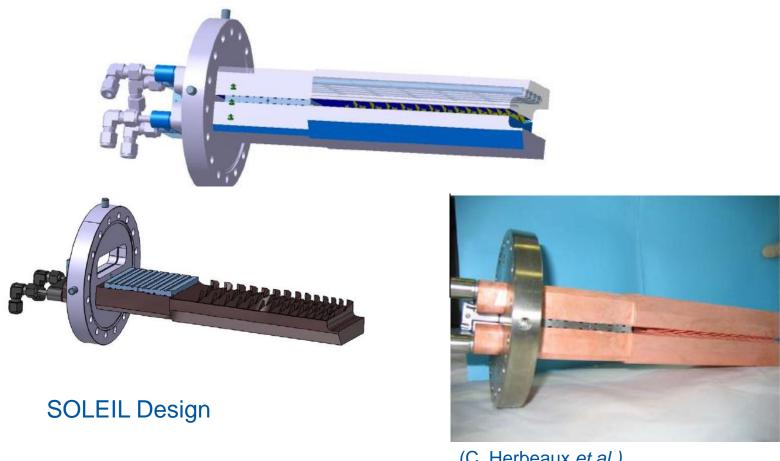
... heavy consequences on design

- Stainless steel
- NEG coated, in-situ baked to 180°C



• A complex vacuum chamber design with a light extraction path, pumping and instrumentation ports and power absorbers (crotch)

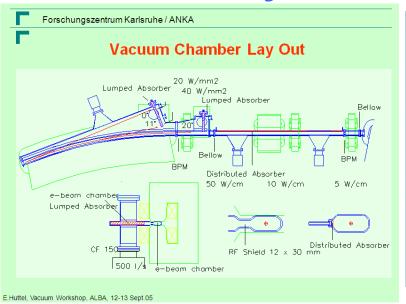
... heavy consequences on design



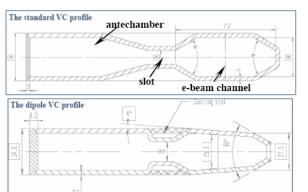
(C. Herbeaux et al.)

Soleil « crotch » power absorber: Water cooled copper Glidcop (256 W/mm²)

heavy consequences on design



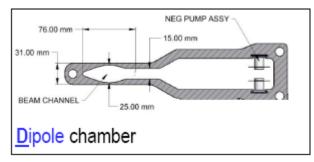




(E. Huttel et al.)

ALBA Design

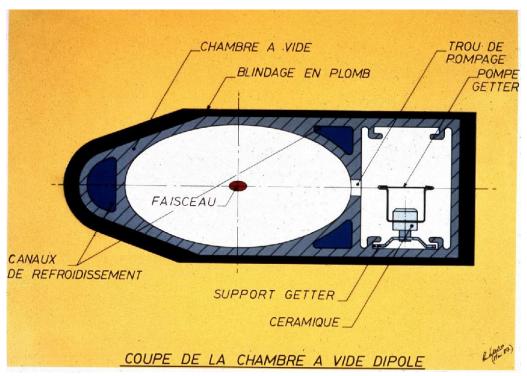
(E. Al-Dmour, EPAC 2006)

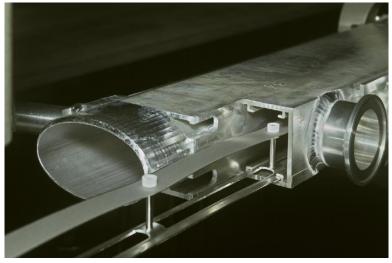


NSLS-2 Design

 Antechamber design to absorb the SR power externally to the beam path with the integration of a distributed pumping

... heavy consequences on design



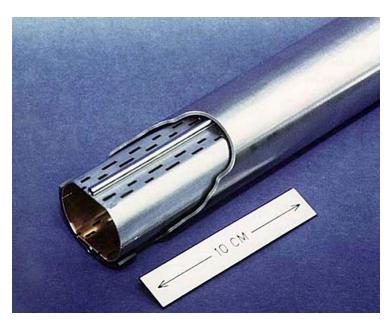


LEP Design

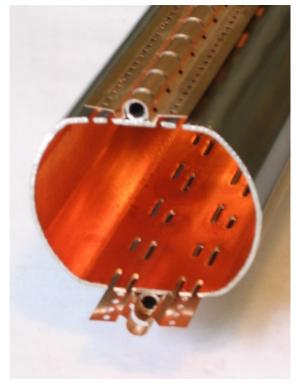
(CERN LEP Vacuum group)

Antechamber and distributed NEG pumping, water cooling and lead shielding

... heavy consequences on design



Courtesy N. Kos CERN TE/VSC



Courtesy N. Kos CERN TE/VSC

LHC Design

(CERN LHC Vacuum group)

 Perforated Cu colaminated beam screen to intercept the SR power protecting the 1.9 K cold bore and to allow a distributed pumping

1.2 Photodesorption

Photodesorption

- The interaction of photons (light) with matters produce the desorption of neutral gases inside the vacuum system
- The photon stimulated desorption (PSD) of physisorbed (meV) or chemisorbed (eV) molecules can be direct or non-direct
- The identified transmitters are photoelectrons, secondary electrons and phonons
- The photon stimulated molecular desorption is a function of the nature of the material, its temperature, its surface state, of the photon energy and the irradiation angle.
- No model exists, therefore in-situ qualification of material is required for the design of a future machine.

Photodesorption: present understanding

- The photodesorption process is linked to the production of photoelectrons and secondary electrons
- Photoelectrons contribute to the gas load by ESD
- The oxide and carbon layers are believed to be the source of gas
- The diffusion of atoms into the solid and their recombination at the surface plays a role

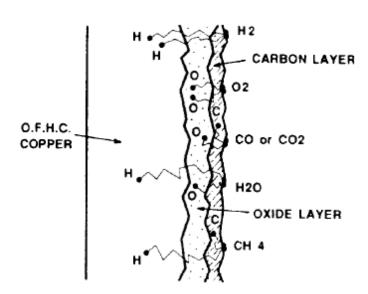


Fig. 6. Tentative Microscopic Model for PSD from OFHC Copper.

O. Gröbner et. al. EPAC 1992

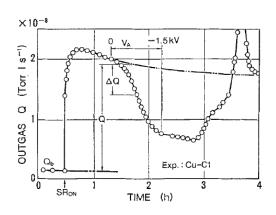
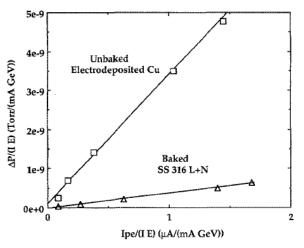


Fig. 5. Changes of outgas due to the bias voltage VA.

T. Kobari *et al* Proc .of Vacuum Design of Synch Light Sources Conference, Argonne, 1990



J. Gómez-Goñi et al. JVSTA 12(4) Jul/Aug 1994, 1714



Dynamic pressure due to PSD

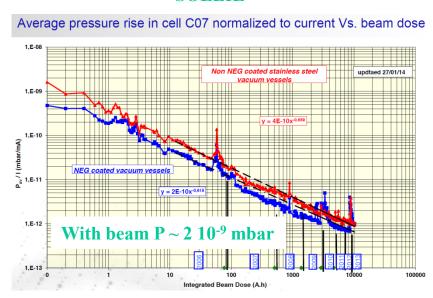
- The dynamic pressure decreases by several orders of magnitude with photon dose: "photon conditioning"
- The photon desorption yield is characterised by η_{photon}

$$P = rac{Q + \eta_{Photons} \overset{ullet}{\Gamma}_{Photons}}{S}$$

Beam cleaning during the first period of LEP 10^{-6} 10^{-7} 10^{-8} 10^{-9} 10^{-10} With beam $P \sim 10^{-10}$ Torn 10^{-11} 10^{-1} 10^{0} 10^{1} 10^{2} 10^{3} 10^{4} 10^{5} Dose (mA h)

O. Gröbner. Vacuum 43 (1992) 27-30

SOLEIL



C. Herbeaux, Journée thématiques RTVide, décembre 2014



Photo-desorption yield measurement

- SR light is extracted from a dipole magnet to irradiate the chamber at ~ 11 mrad
- SR fan is vertically collimated therefore photon flux < 4 eV are attenuated
- The gas load is measured by the throughput method via a conductance (72.5 l/s for N₂)

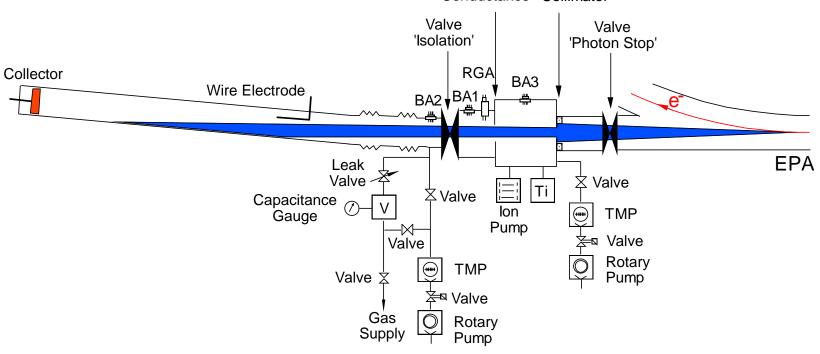
• A wire and a collector are biased for current measurement to estimate the photon reflectivity and

photoelectron yield $Q_0 = C (P_2 - P_1)$ $Q = \eta \dot{\Gamma} + Q_0 = C (P_2' - P_1')$

$$\eta = \frac{G}{\dot{\Gamma}} C (\Delta P_2 - \Delta P_1) \approx \frac{G}{\dot{\Gamma}} C \Delta P_2$$

Conductance Collimator

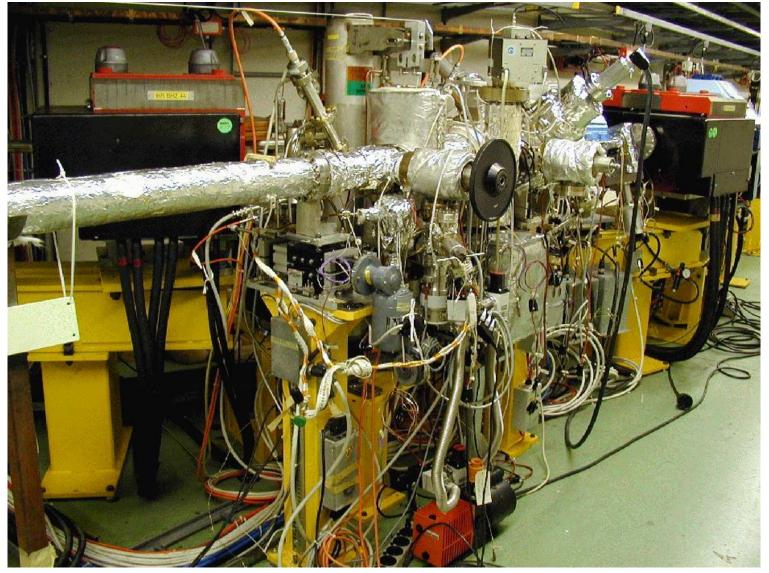
With G = 4.3 10¹⁹ molecules/mbar.l



J. Gómez-Goni et al. J. Vac. Sci. Technol. A 12(4), Jul/Aug 1994, 1714

V. Baglin et al. EPAC 1998, Stockholm, Sweden.

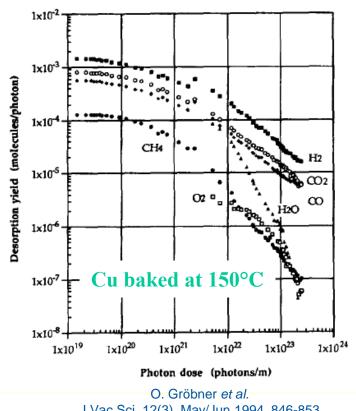
CERN EPA Synchrotron Light Facility 42 - 1999

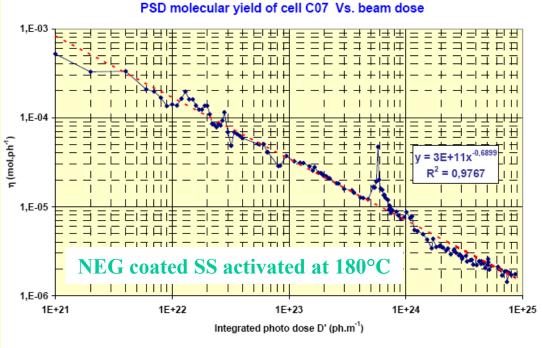


The LEP Pre-Injector as a multipurpose facility, J-P. Potier, L. Rinolfi, EPAC 1998, Stockholm, Sweden, 1998

Conditioning under photon irradiation

Typical desorption yield range: from 10⁻³ molecule/photon to 10⁻⁶ when conditioned





C. Herbeaux et. al. EPAC 2008, Gênes, Italie

J. Vac. Sci. 12(3), May/Jun 1994, 846-853

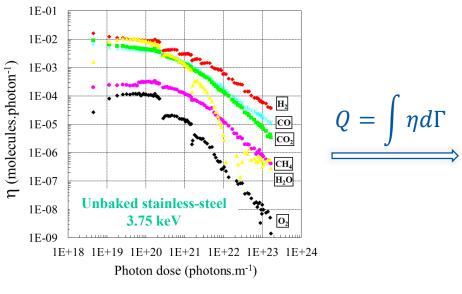
$$oldsymbol{\eta_{Photons}} = oldsymbol{\eta_{0}}{\left(rac{ ext{D}}{ ext{D}_{0}}
ight)}^{-a}$$

 The hydrogen desorption is characterised by a diffusion process: a = 0.5

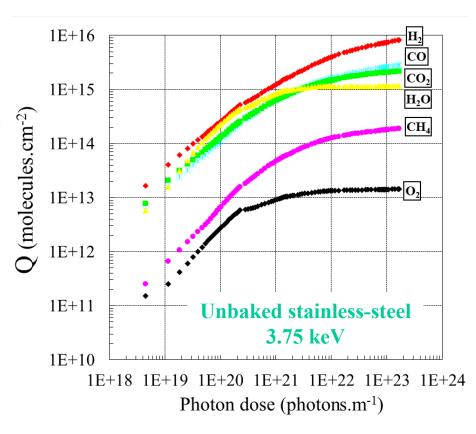
M. Andritschky et al., Vacuum 38 (8-10), 933, (1988)

Gas load

The total desorbed quantity amounts to 15 monolayers for an unbaked system



Gas	H ₂	CH ₄	H ₂ O	СО	CO ₂	Total
molecules/ cm ² x 10 ¹⁵	8.1	0.2	1.1	2.8	2.2	14.4

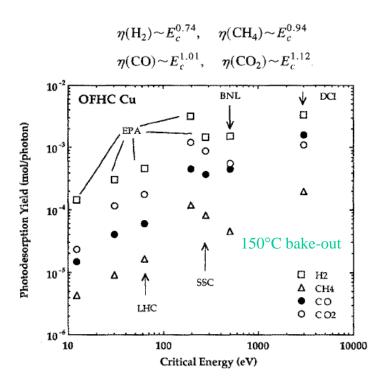


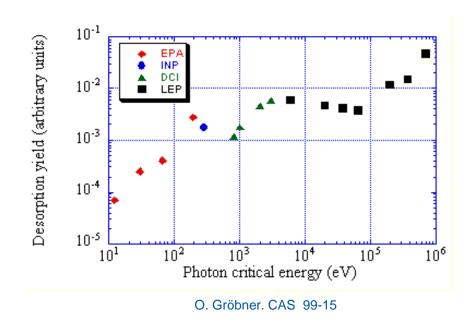
C. Herbeaux et al. JVSTA 17(2) Mar/Apr 1999, 635



Evolution with critical energy

- At low energy, the photoelectric effect dominates
- Above a few 100 keV, Compton diffusion dominates and produce a cascade of energetic recoil electrons with a diffusion of secondary photons





J. Gómez-Goñi et al. JVSTA 12(4) Jul/Aug 1994, 1714



Photodesorption of NEG films

- Very low desorption yields
- Be aware of the difference between effective and intrinsic yields

$$\eta_{intrisic} \simeq \left(\frac{S}{C} + \sqrt{\frac{S}{C_t}}\right) \times \eta_{effective}$$

V. Baglin et al. CERN VTN 98-04, 1998.

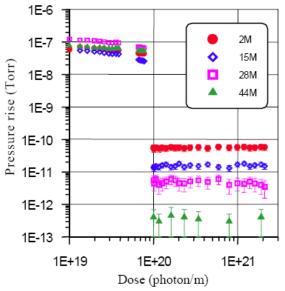


Figure 2: Pressure rise measured in the centre of the TiZrV coated test chamber before activation ($<1\cdot10^{20}$ photons/m) and after activation ($>1\cdot10^{20}$ photons/m).

Table 1: Summary of results from the non-activated test chamber

Gas	Sticking probability	Photodesorption yield (molecules/photon)
H ₂	0	1.10-3
CH ₄	0	2.5·10 ⁻⁴
CO	0	5·10 ⁻⁴
CO ₂	0	3·10 ⁻⁴

Baked at 80°C

Table 2: Summary of results from the activated test

Gas	Sticking probability	Photodesorption yield (molecules/photon)			
H_2	~0.007	~1.5·10 ⁻⁵			
CH ₄	0	2·10 ⁻⁷			
CO (28)	0.5	<1.10-5			
$C_xH_y(28)$	0	<3·10 ⁻⁸			
CO ₂	0.5	<2·10 ⁻⁶			

TiZrV film on stainless-steel 4.5 keV

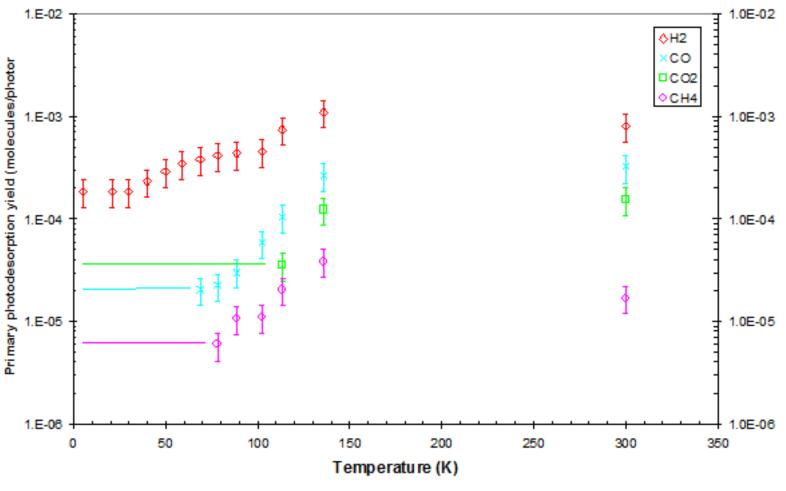
V. Anashin et al. EPAC 2002, Paris, France.

Activated at 190°C



Photodesorption at Cryogenic Temperature

• Initial yield, η_0 , are smaller than at room temperature



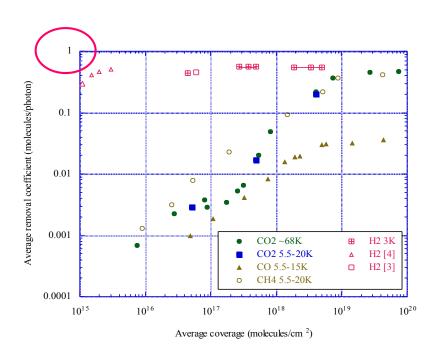




What about physisorbed molecules?

Desorption of physisorbed molecules

Photo-cracking of molecules



V. Anashin et al., Vacuum 53 (1-2), 269, (1999)

Stainless steel
250-300 eV
Perpendicular incidence

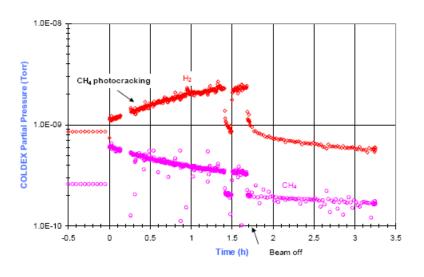


Figure 5 : \sim 10 monolayers of CH₄ condensed onto a BS without hole prior to irradiation at 6 K

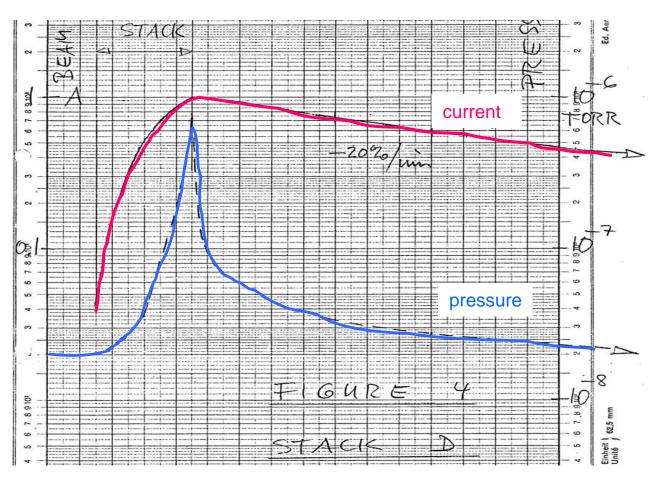
V. Baglin et al. EPAC 2002, Paris, France.

2. Vacuum instability and ion stimulated desorption

The phenomenon

High current machines: ISR, LHC ...

- Beam current increases to 1 A
- Pressure increases up to 10⁻⁶ Torr (x 50 in a minute)
- Beam loss



First documented pressure bump in the ISR

E. Fischer/O. Gröbner/E. Jones 18/11/1970



The mechanism of vacuum instability

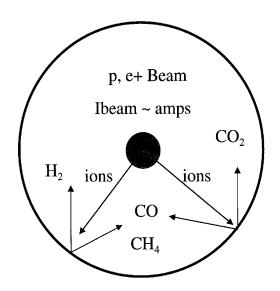
Origin are ions produced by beam gas ionisation

$$V\frac{dP}{dt} = Q_0 + \eta_{ion}\sigma \frac{I}{e}P + C\frac{d^2P}{dx^2}$$

Quasi stationary long tube (C=0)

$$Q_0 + \eta_{ion} \sigma \frac{I}{e} P = P S_{eff}$$

$$P = \frac{Q_0}{S_{\text{eff}} \left(1 - \frac{\eta_{\text{ion}}}{S_{\text{eff}}} \sigma \frac{I}{e} \right)}$$



• When the beam current approach the **critical current**, the pressure increases to infinity

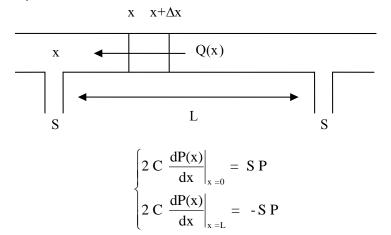
$$(\eta_{\text{ion}} I)_{\text{crit}} = \frac{e S_{\text{eff}}}{\sigma}$$

Description of the mechanism

In the case of a machine with distributed pumping (C≠0):

$$\frac{d^2P}{dx^2} = -\frac{Q}{C} - \frac{\eta_{ion}\sigma \frac{I}{e}}{C}P = -\frac{Q}{C} - \omega^2 P$$

$$P(x) = \frac{a}{C \omega^{2}} \left[\frac{\cos(\omega(L/2 - x))}{\cos(\omega L/2) - \frac{\omega C}{S/2} \sin(\omega L/2)} - 1 \right]$$



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When the denominator approach zero, the pressure diverge

$$\cos\left(\omega \frac{L}{2}\right) - \frac{\omega C}{\frac{S}{2}}\sin\left(\omega \frac{L}{2}\right) > 0 \iff \omega \tan\left(\omega \frac{L}{2}\right) < \frac{\frac{S}{2}}{C} \implies \left(\omega \frac{L}{2}\right) < \frac{\pi}{2}$$

so
$$\eta_{ion} I < \frac{\pi^2 C e}{410^3 (L/2) \sigma}$$
 therefore $(\eta_{ion} I)_{crit} = \frac{\pi^2 C e}{410^3 (L/2) \sigma}$

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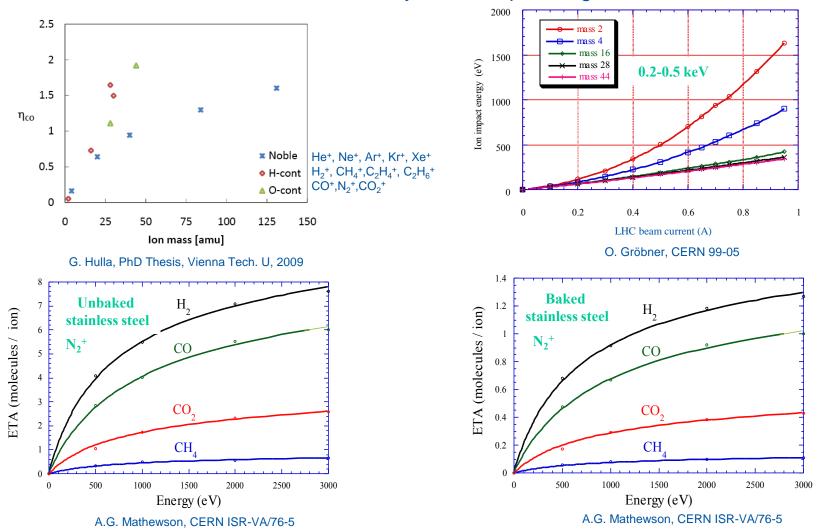
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$$(\eta_{\text{ion}} I)_{\text{crit}} = \frac{\pi^2 C e}{410^3 (L/2)\sigma}$$

In the case of more complex geometry, numerical tools are used

Ion desorption yield

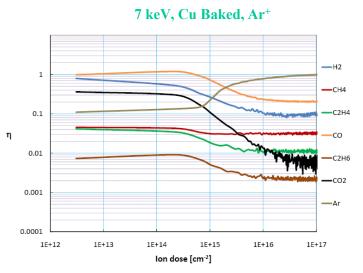
- Varies with the material, the ion energy and ion species
- Several units of molecules can be desorbed by ions → Sputtering



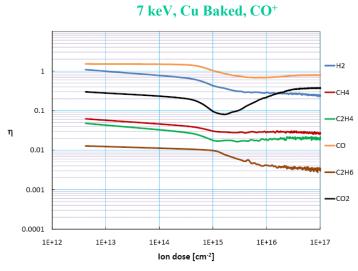


Conditioning and implantation

A conditioning is observed but at high dose, some ions can be implanted!



G. Hulla, PhD Thesis, Vienna Tech. U, 2009



G. Hulla, PhD Thesis, Vienna Tech. U, 2009

- In the LHC: the maximum flux is about 3 108 ions/(cm².s) i.e. a dose of 3 1015 ions/(cm².year)
- In the LHC, there is no "beam" conditioning under ion bombardment

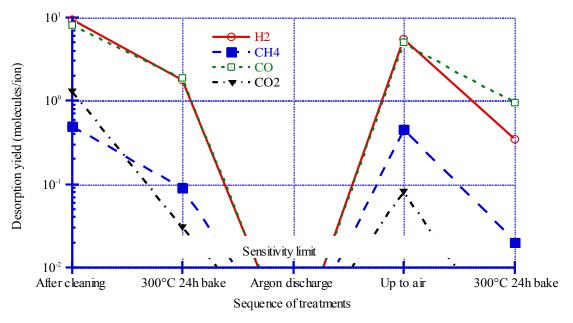
How to ensure vacuum stability?

• Beam conditioning being negligible, one must decrease the desorption yield and optimise

the pumping speed

 $I_{crit} = \frac{1}{\eta_{ion}} \frac{eS}{\sigma}$

• ISR: Argon glow discharge (Ar, 10 % O₂,~ 400 V, 10¹⁸ Ar/cm²)) with *in-situ* bakeout:



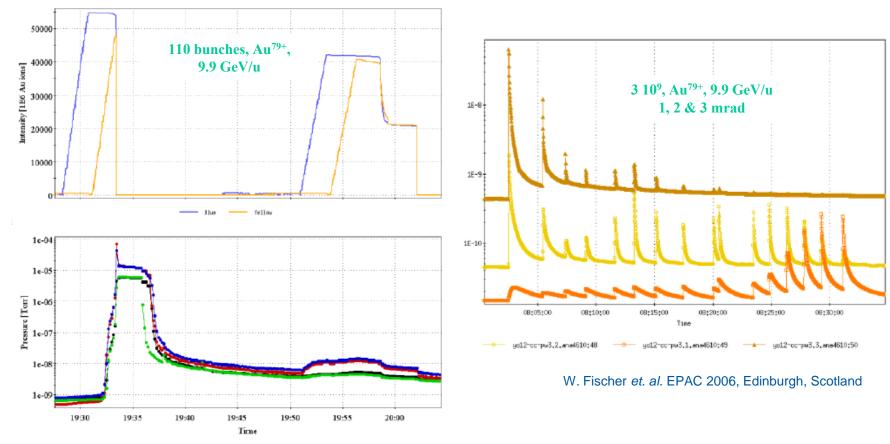
A.G. Mathewson, CERN ISR-VA/76-5



3. Particle losses and ion stimulated desorption

RHIC

• Loss of ions from a beam leads to large pressure increases: 10⁻⁸ ...10⁻⁵ mbar!



W. Fischer et. al. EPAC 2002, Paris, France



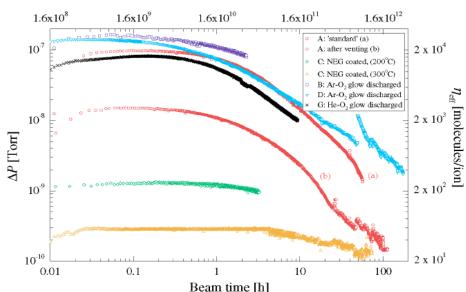
High energy ions

• Desorption yields range from 20 – 20 000 molecules per ion

Dose [ions/cm²]

Pb⁵³⁺, 4. 2 MeV/u, 14 mrad

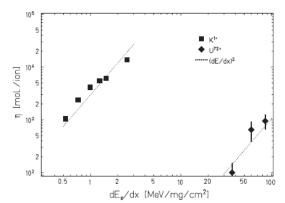
E. Mahner *et al.* , Phys. Rev. ST Accel. Beams 6, 013201 (2003)



• The desorption is determined by the energy given to the electrons (electronic stopping force)

$$\eta_{ion} \propto \left(\frac{dE_e}{dx}\right)^2$$

L. Prost et al., PRL 98, 064801 (2007)



• The desorption induced by the electrons is the responsible mechanism



Intercept ion loss on dedicated collimators:

- LEIR: 30 μm gold film on SS 316 LN, perpendicular incidence

- GSI : 0.1 μm gold film, perpendicular incidence. Absorbeur inserted in a secondary vacuum chamber. NEG film

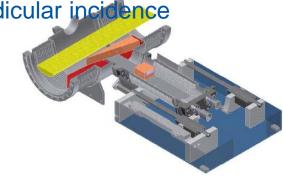
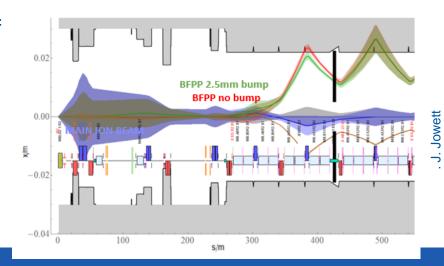


Figure 2: Horizontal cut through the installed SIS18 ion catcher prototype. Yellow: beam, red: secondary chamber, brown: beam absorbers.

 HL-LHC: movable collimator – 150 W of 7 ZxTeV ions coming from BPFP

BFPP:

$$^{208}Pb^{82+} + ^{208}Pb^{82+} \rightarrow ^{208}Pb^{82+} + ^{208}Pb^{81+} + e^{+}$$



HL-LHC ions collimator

- Located in the LHC arcs around IP2
- W jaws





Courtesy S. Redaelli, F. Savary

4. Electron cloud and related surface parameters

4.1 Introduction

History: observed at the ISR

- Vacuum stability test of a baked aluminium chamber 200°C, diam 160 mm (1976-1977)
- Observation of pressure spikes, particularly during transverse displacement of a proton bunch
- The existence of the spike varies with :
 - bunch length
 - number of proton bunch
- Existence of a current threshold (120 mA for 20 bunches)
- Different gas composition (dominated by H₂ instead of CO)
- Measurement of a significant electron current on the clearing electrodes
 - Gas desorption is stimulated by electrons
 - Electrons are accelerated by the proton bunch: multipactor effect

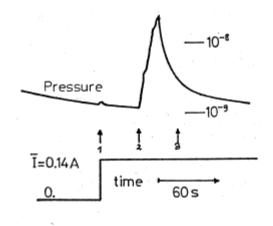


Fig. 1. Pressure spike observed during slow displacement of a bunched beam across the aperture :

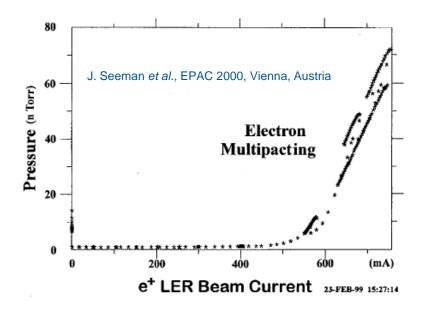
1 injection - 40 mm, 2 - 10 mm and 3 + 10 mm radial position from centre of the vacuum chamber

O. Gröbner, ISR-VA/77-38



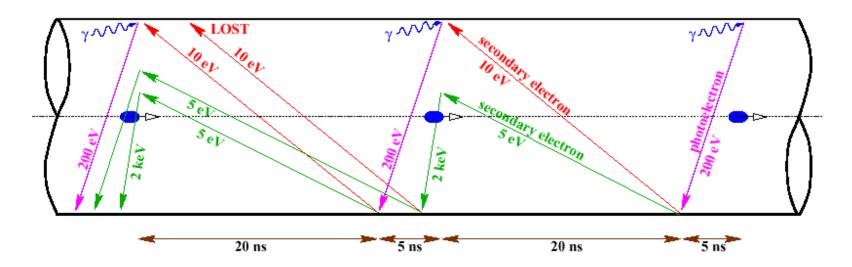
PEP-II

- Electron cloud in the positron ring was foreseen during the design phase: TiN coating on Aluminium
- Emittance blow up above 800 mA (SR light)
- Observation of non linear pressure rise
- Winding of solenoids in the straight section
 - Luminosity increase





LHC mechanism



Schematic of electron-cloud build up in the LHC beam pipe.

F. Ruggiero et al., LHC Project Report 188 1998, EPAC 98

- Key parameters:
 - beam structure
 - bunch current
 - vacuum chamber dimension
 - secondary electron yield
 - photoelectron yield
 - electron and photon reflectivities

. . .

$$P = \frac{Q + \eta_{Electrons} \overset{\bullet}{\Gamma}_{Electrons}}{S}$$

How to mitigate the electron cloud?

- Once again, play with the key parameters :
 - Reduce the photoelectron yield (grazing incidence has larger yield than perpendicular incidence)
 - Reduce the secondary electron yield (scrubbing, NEG or amorphous carbon films, geometry)
 - Reduce the amount of electrons in the system (solenoid magnetic field, clearing electrodes, material reflectivity)
 - Adapt the beam structure or the vacuum chamber dimensions to reduce the multiplication

. . .



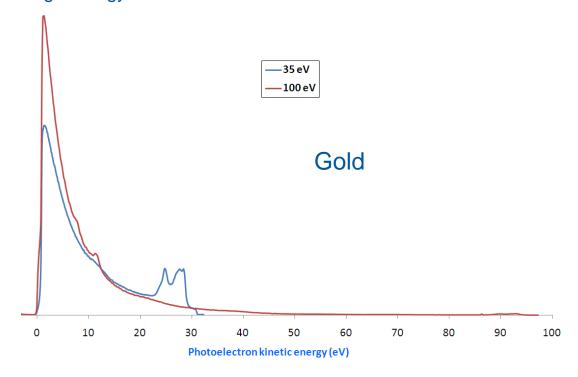
Vacuum, Surfaces & Coatings Group

Technology Department

4.2 Photons from SR

Photoelectrons

- Photoelectric effect: when a photons irradiates a surface with enough energy, it produces electrons
- The energy of emitted electrons varies from :
 0 eV to (hv W_f) eV
- Most of the electrons are secondaries
- A few 0.1 % to 1 % have high energy

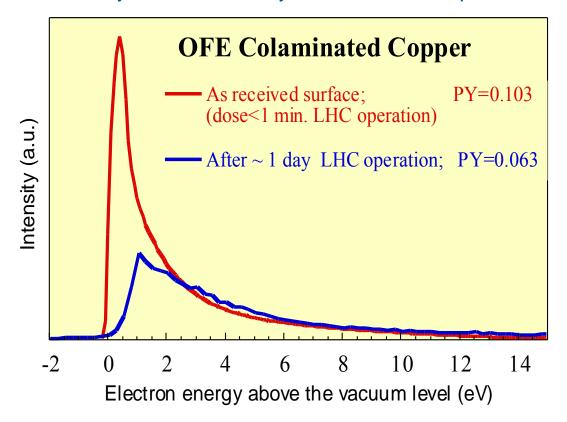


R. Cimino et al., Phys. Rev. ST Accel. Beams 2, 063201 (1999)



EDC under SR irradiation

- EDC: Electron distribution curve
- SR dose reduce the amount of low energy photoelectrons
- The total yield is decreased by 40 % after 1 day of nominal LHC operation



R. Cimino et al. Phys. Rev. AB-ST 2 063201 (1999)

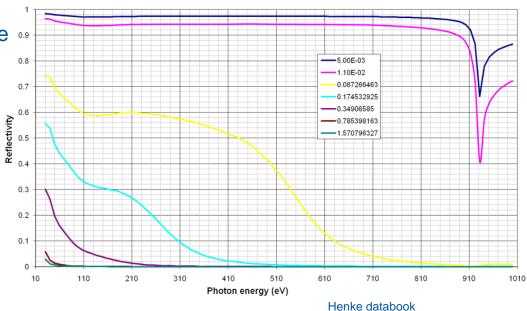
Photon reflectivity

- From 1 to 80% forward reflectivity
- Low reflectivity at perpendicular incidence
- High reflectivity at grazing incidence *i.e.* this is the case of SR in accelerators
- In LHC, 5 mrad gives more than 95% reflection
- Copper adsorption at 920 eV

		45 eV	194 eV	
Material	Status	R (%)	R (%)	
Cu roll	as-received	80.9	77.0	
bonded				
Cu roll	as-received	21.7	18.2	
bonded air				
baked				
Cu	as-received	5.0	6.9	
electroplated				
Cu sawtooth	as-received	1.8	-	
	150°C, 9 h	1.3	1.2	
	150°C, 24 h	1.3	1.2	
TiZr film	as-received	20.3	17.1	
	120°C, 12 h	19.5	16.7	
	250°C, 9 h	19.9	17.4	
	350°C, 10 h	20.6	16.9	
	CO saturated	20.7	-	

V. Baglin et al., Trieste, 1998

Copper reflection for unpolarised photon with 0 Angstreom roughness



DCI, Ec=3 keV



O. Gröbner et al., 24-4-1988

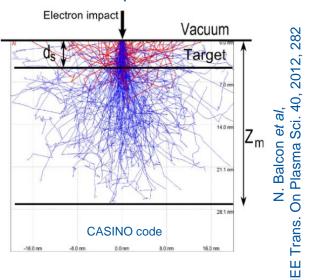
→ In complex geometries, ray tracing is done with e.g. Synrad



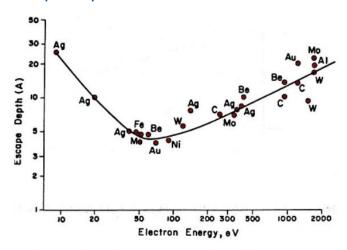
4.3 Electrons from the electron cloud

Electron Distribution Curve (EDC)

• Penetration depth: 1 – 10 nm

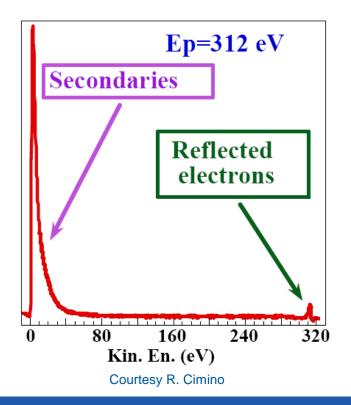


• Escape depth: <10 nm



Mean escaped depth of electrons in solids and "universal" curve.

- The electron distribution curve shows :
 - Component at reflected electron energy
 - Secondary electrons with low energy
- most of the emitted electrons have low energy



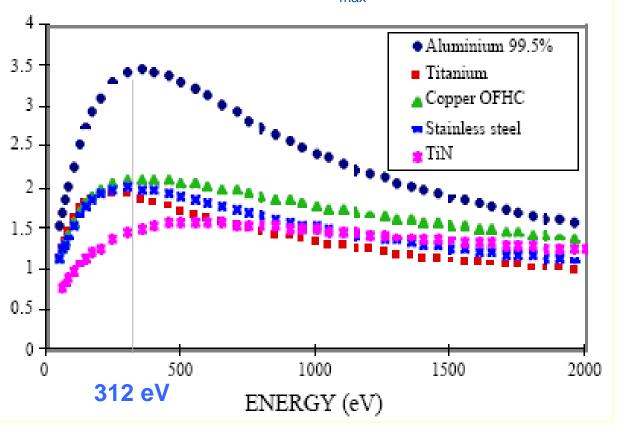




Secondary Electrons Curve

$$\delta = \frac{number\ of\ produced\ electrons}{incident\ electrons}$$

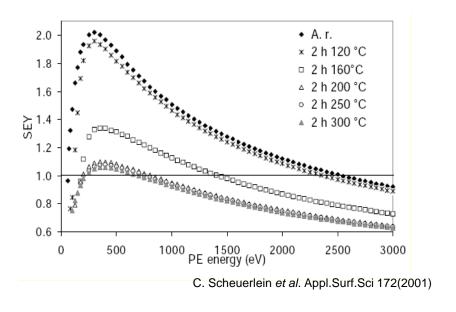
- Technical material
- Maximum around 200-300 eV
- δ_{max} ~ 2 to 3.5

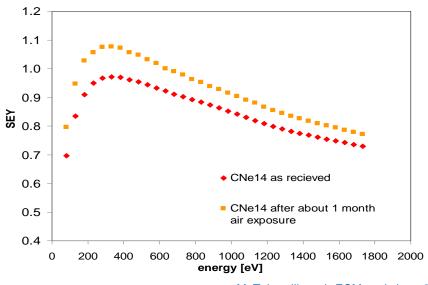


N. Hilleret et al., LHC Project Report 433 2000, EPAC 00



Very Iow SEY





M. Taborelli et al., ECM workshop, 2008

Amorphous carbon

• TiZrV film

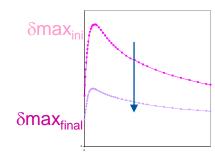
The origin of the low SEY is different in both case :

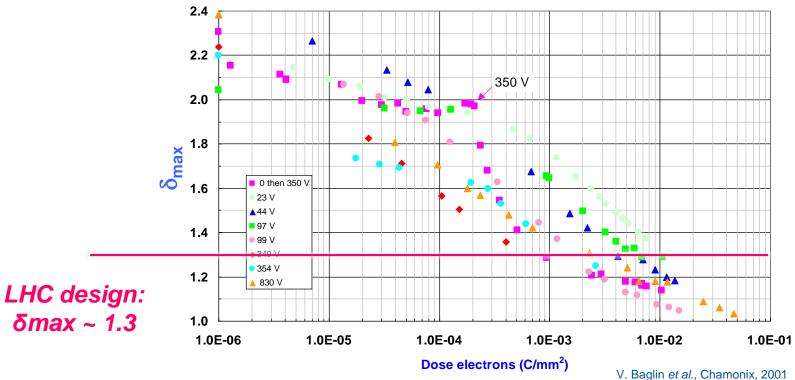
- nature of the surface
- smooth versus rough surfaces



LHC: Scrubbing of the surface

- Photoelectrons produced by SR are accelerated towards the test sample
- Reduction of SEY under electron irradiation is observed
- 1 to 10 mC/mm² is required
- Growth of a carbon layer (AES, XPS)

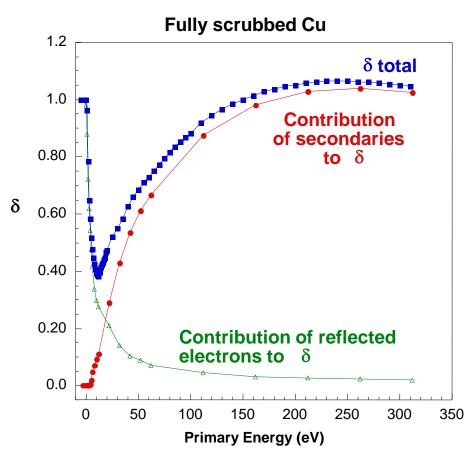




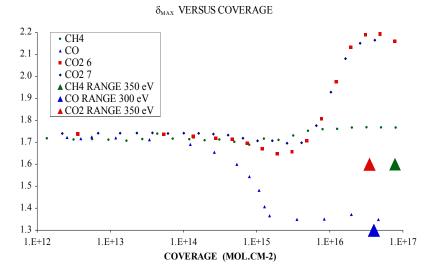


SEY at cryogenic temperature

• Beam scrubbing at 10 K but SEY increases with gas condensation

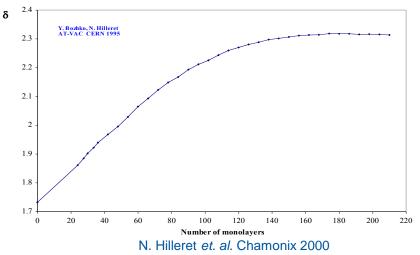


R. Cimino, I.R. Collins, App. Surf. Sci. 235, 231-235, (2004)



N. Hilleret. LHC MAC December 2004

Variation of maximum yield with amount of adsorbed water





Electron desorption yield

- Unbaked copper
- Threshold around 10 eV

$$\eta(E) = \eta_0 \left(\frac{E - E_c}{300 - E_c} \right)^{0.85}$$

Table 1: Fit parameters

	η_0 / (molec./e ⁻)	E_C / eV
C_2H_6	1.1×10^{-1}	11.4
CH_4	2.1×10^{-2}	7.5
CO	5.8×10^{-2}	7.2
CO_2	2.7×10^{-1}	9.1
H_2	1.9×10^{0}	12.7
$_{\mathrm{H_2O}}$	3.1×10^{-2}	-22.9

$$\eta = \frac{number\ of\ desorbed\ molecules}{incident\ electrons}$$

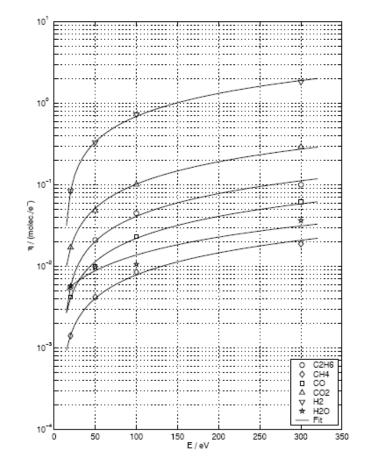


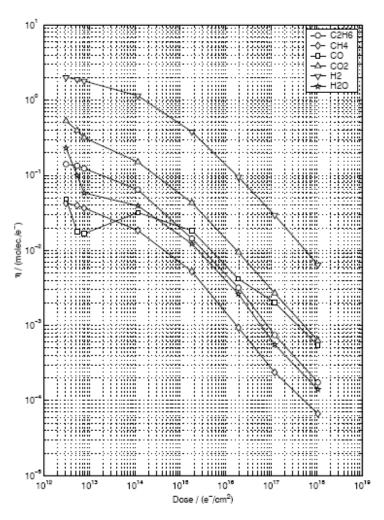
Figure 5: Electron induced desorption yield as a function of the electron energy. The values for 20, 50, and 100 eV have been obtained by interpolation between the two measurements shown in figure 4 at a constant dose of 1.4×10^{14} e⁻/cm².

G. Vorlaufer et al., CERN VTN, 2000



Electron dose

• Reduction of the electron desorption yield with the electron dose



$$\eta(D) = \eta_0 \left(\frac{D}{D_0}\right)^{-a}$$

	H ₂	CH ₄	H ₂ O	СО	CO ₂
η_0	2 10-1	2.5 10-2	1 10-1	3.5 10-2	5 10 ⁻²
D ₀ x 10 ¹⁴	3	1	6	2	4
а	0.47	0.62	0.66	0.49	0.54

Figure 3: Effect of the electron dose on the electron induced desorption yield of an unbaked copper sample. The electron energy during bombardment and measurement was 300 eV.



Electron desorption at cryogenic temperature: Cu

- The yields are very large and range from 0.1 to 50
- For a monolayer (10¹⁵ molecules/cm2)

	H ₂	CH ₄	СО	CO ₂
η	500	5	10	0.5

Studied for 300 eV electrons with:

- 1) Pure gas
- 2) Equimolecular mixture of 4 gases
- 3) Standard LHC gas composition

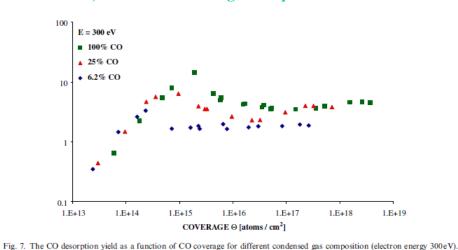


Fig. 5. The H2 desorption yield as a function of H2 coverage for different condensed gas composition (electron energy 300 eV).

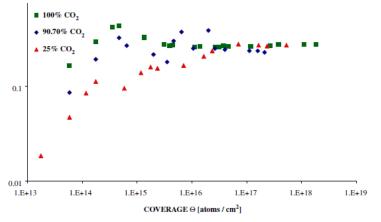


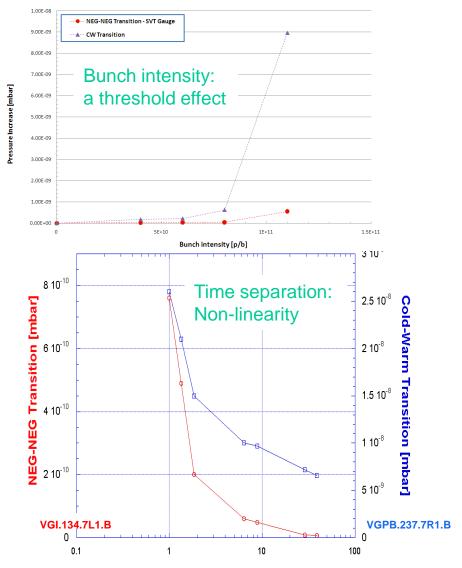
Fig. 8. The CO2 desorption yield as a function of CO2 coverage for different condensed gas composition (electron energy 300 eV).

H. Tratnik et al., Vacuum 81, 731,(2007)

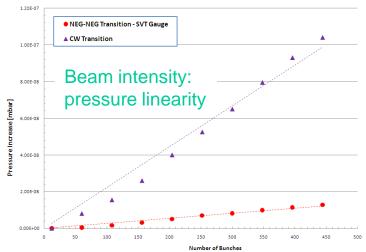


4.5 Beam structure

Multipacting: Influence of Beam Structure

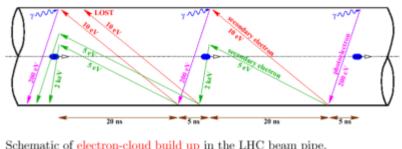


Bunch Separation Time of the 24+24 Bunches [µs]



G. Bregliozzi et al., IPAC San Sebastian, 2011

$$P = rac{Q + \eta_{Electrons} \overset{ullet}{\Gamma}_{Electrons}}{S}$$



Schematic of electron-cloud build up in the LHC beam pipe.

F. Ruggiero et al., LHC Project Report 188 1998, EPAC 98



Lecture 4 summary

- In accelerators, the circulating beam can contribute to stimulate molecular desorption
- Those phenomenon can lead to much larger gas load than the thermal outgassing rate
- Photon stimulated desorption originates from SR
- Ion stimulated desorption originates from beam gas ionisation and can lead to vacuum instability
- Particle losses
- Electron stimulated desorption originates from an electron cloud

Some References

- Cern Accelerator School, Vacuum technology, CERN 99-05
- Cern Accelerator School, Vacuum in accelerators, CERN 2007-03
- Cern Accelerator School, Vacuum for particle accelerators, Glumslov, June 2017
- The physical basis of ultra-high vacuum, P.A. Redhead, J.P. Hobson, E.V. Kornelsen. AVS.
- Scientific foundations of vacuum technique, S. Dushman, J.M Lafferty. J. Wiley & sons.
- Les calculs de la technique du vide, J. Delafosse, G. Mongodin, G.A. Boutry. Le vide.
- Vacuum Technology, A. Roth. Elsevier Science
- Foundations of vacuum science and technology, Ed by J.M. Lafferty. J. Wiley & sons.
- Vacuum in Particle Accelerators: Modelling, Design and Operation of Beam Vacuum Systems, O. Malyshev. Wiley VCH.

Some Journals

- Journal of Vacuum Science and Technology
- Vacuum
- Applied Surface Science
- Nuclear Instruments and Methods
- Physical Review Accelerator and Beams



Thank you for your attention !!!





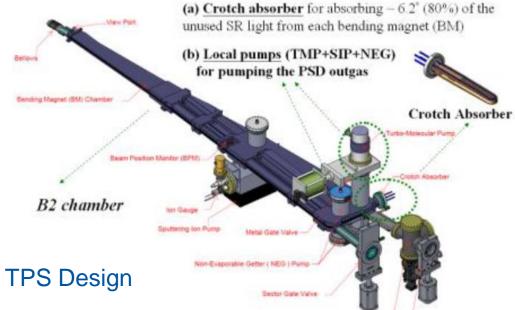
Complementary information

1.1 Synchrotron radiation

Complementary information

- Extruded Aluminum
- Ex-situ baked to 150°C





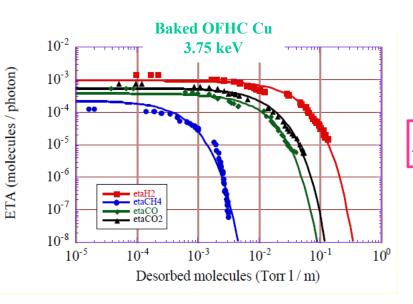
G.Y Hsiung et al.

• A complex vacuum chamber design with a light extraction path, pumping and instrumentation ports and power absorbers (crotch)

1.2 Photodesorption

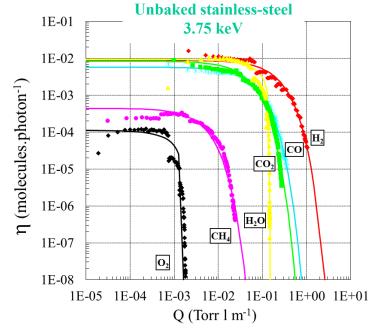
Desorption yield vs gas load

• The quantity removed during the cleaning process is a useful information to estimate intervals between getter reactivation or surface coverage on a cryogenic surface



O. Gröbner *et al.* J.Vac.Sci. 12(3), May/Jun 1994, 846-853

	H ₂	CH₄	СО	CO ₂
η_0 (molecules/ph)	9.2 10-4	2.3 10-4	3.7 10-4	5.5 10-4
Q _o (Torr I /m)	3.0 10-2	4.5 10-4	8.4 10-3	1.1 10-2
Q ₀ (molecules/cm ²)	2.3 1014	3.5 1012	6.5 10 ¹³	8.5 10 ¹³



C. Herbeaux et al. JVSTA 17(2) Mar/Apr 1999, 635

H ₂	CH₄	СО	CO ₂
8.8 10 ⁻³	4.4 10-4	5.7 10 ⁻³	8.4 10 ⁻³
1.9 10-1	3.9 10 ⁻³	5.7 10-2	4.0 10-2
1.5 10 ¹⁵	3.1 10 ¹³	4.5 1014	3.2 1014



2. Vacuum instability and ion stimulated desorption

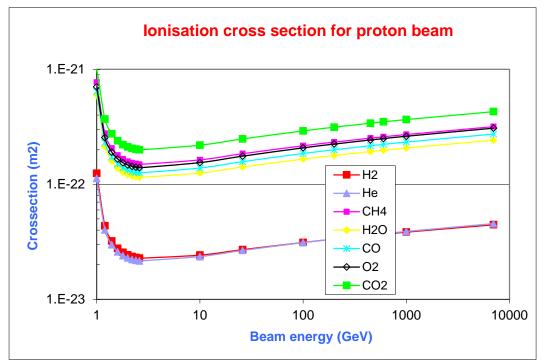
Ionisation cross section

• It is a function of the speed & the charge of the projectile and of the nature of the residual gas.

$$\sigma = 4\pi \left(\frac{h/2\pi}{m_{e}c}\right)^{2} \frac{Z^{2}}{\beta^{2}} \left[M^{2} \left(\ln \left(\frac{\beta^{2}}{1-\beta^{2}} \right) - \beta^{2} \right) + C \right]$$

F.F. Rieke, W. Prepejchal , Phys. Rev. A5, 1507 (1972)

	Ionisation cross-section (in 10 ⁻¹⁸ cm ²)					
Gas	26 GeV 450 GeV 7000 GeV					
H_2	0.27	0.36	0.45			
Не	0.27	0.36	0.45			
CH_4	1.9	2.5	3.2			
H ₂ O	1.4	1.9	2.4			
\tilde{N}_2	1.6	2.2	2.7			
CO	1.6	2.2	2.7			
O_2	1.8	2.4	3.1			
Ar	1.7	2.4	3.1			
CO ₂	2.5	3.4	4.3			



Heavy gas must be avoided



Ion desorption

S(E) Complementary information

- Described by the nuclear and electronic stopping force (stopping power)
 - Low masses (H₂) are desorbed by the electronic energy transfer to the lattice
 - High masses are desorbed by the direct nuclear momentum transfer between two particles

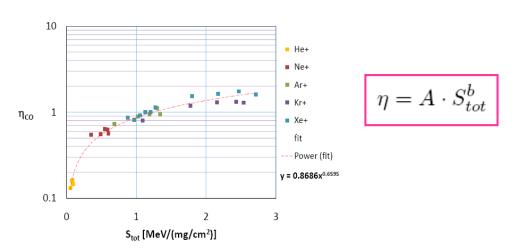


Figure 6.43: CO desorption yields as a function of the total energy loss obtained for noble gas ions incident on copper.

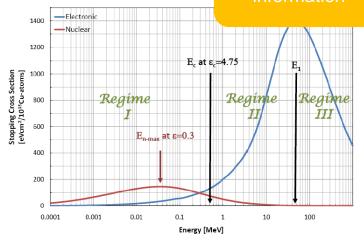


Figure 4.3: Electronic and nuclear stopping cross sections for Ar⁺-ions incident

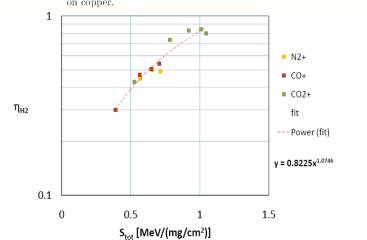


Figure 6.48: H_2 desorption yields as a function of the total energy loss obtained for N_2^+ -ions and oxygen containing ions incident on copper.

G. Hulla, PhD Thesis, Vienna Tech. U, 2009



At cryogenic temperature

1E+05

Complementary information

→ 0.5 keV

- 1 keV

→ 5 keV

10 keV

1E+20

Desorption of physisorbed gas

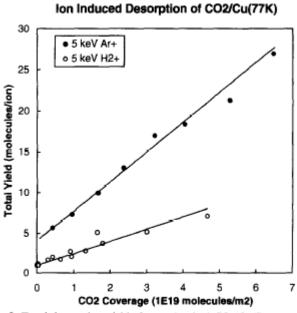
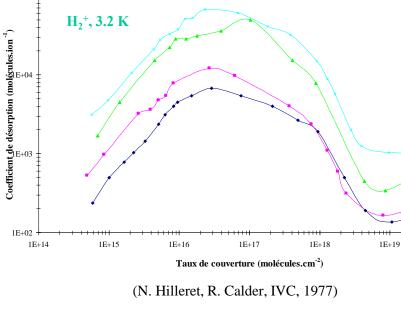


Figure 2. Total desorption yields from adsorbed CO₂/Cu(77K) induced by bombardment of 5 keV H₂⁺ and Ar⁺ ions, plotted as a function of CO₂ dose. The lines indicated are best fit lines drawn by eye through experimental points.

J. Barnard et al., Vacuum 47 (4), 347, (1996)



$$\eta'_{H2} \sim 2000$$
 $\eta'_{CO2} \sim 2$
@ 5 keV and 1 monolayer

• Critical current is changed to
$$I_c = \frac{\alpha S}{\left(\eta_{ion} + \eta_{ion}^{'}\right)^{O}}$$

•It is a function of the geometry, the gas specie, the sticking coefficient and of the 2 desorption



LHC beam screen stability

• A minimum pumping speed is provided beam the beam screen's holes

$$(\eta_i I)_{\text{crit}} = \frac{e}{\sigma} S_{\text{eff}}$$

	H ₂	CH ₄	CO	CO ₂
(η <i>I</i>) _{crit} [A]	1300	80	70	35



Courtesy N. Kos CERN TE/VSC

Beam screen's holes provide room for LHC upgrades

• NB: In the long straight sections, vacuum stability is provided by TiZrV films and ion pumps which are less than 28 m apart

• The ion flux is a <u>function of</u> the pressure and the beam current

$$\dot{\Gamma}_{\text{ion}} = \sigma \frac{I}{e} P \approx 310^8 \text{ ions/cm}^2/\text{s} = 310^{11} \text{ ions/m/s}$$

- For nominal parameters, P~ 10⁻⁸ mbar and I ~ 600 mA
- Ion energy will be about 100 eV, so the desorption yield about 2 molecules/ion

$$Q = \frac{\eta \Gamma}{3.310^{19}} = 2 \ 10^{-8} \ \text{mbar.} \ell/\text{s/m}$$

Beam screen pumping speed, S

$$S = 3.63 \,\mathrm{A} \sqrt{\frac{\mathrm{T}}{M}} \cong 1000 \,\ell/\mathrm{s/m}$$

Pressure increase due to ion:

$$\Delta P = \frac{Q}{S} = 10^{-11} \text{ mbar}$$
 \rightarrow No visible pressure increase in LHC



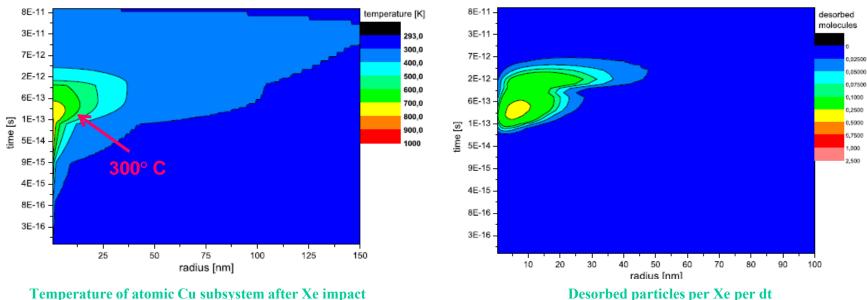
3. Particle losses and ion stimulated desorption

- Surface effect (except diffusion H₂) due to a thermal activation
- « Inelastic thermal spike model »: a temperature map coupled to the thermal desorption model

$$\eta = \int_0^{t_{max}} \int_0^{r_{max}} v_0(T(r,t)) \cdot \tilde{n}(r,t) \cdot \exp\left(-\frac{E_{des}}{k_B \cdot T(r,t)}\right) \cdot 2\pi \cdot r dr dt,$$

M. Bender et al., NIM B 267 (2007) 885-890

Xe²⁹⁺, 1.4 MeV/u, Perpendicular



Temperature of atomic Cu subsystem after Xe impact

$$\eta_{calculated} \!=\! 185$$

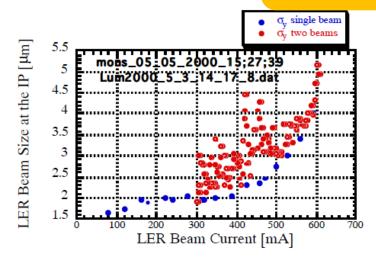
4. Electron cloud and related surface parameters

4.1 Introduction

- Cu OFHC vacuum chamber, unbaked, NEG pumping
- Emittance blow up in the vertical plane of the positron beam
- Positron bunch instability due to the cloud of photoelectrons
- Observed in multibunch mode

K. Ohmi, F. Zimmermann, PRL 85, 3821 (2000)

- Installation of permanent magnets then solenoids
 - Luminosity increase



Observation at IP

Y. Funakoshi et al., EPAC 2000, Vienna, Austria



KEKB LER Solenoids



RHIC

Complementary information

- Stainless steel vacuum chamber baked at 250°C in the straight sections
- Stainless steel vacuum chamber cooled at 4 K in the arcs
- Pressure increase with protons and ions beams
- NEG, bakeout, solenoids, beam structure

→ Luminosity increase

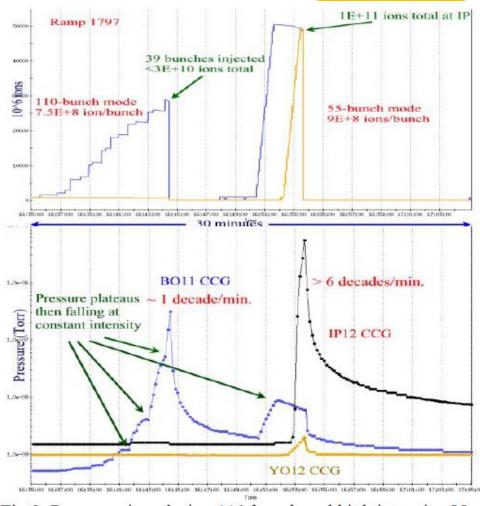


Fig 2. Pressure rises during 110-bunch and high intensity 55-bunch mode Au operations. H. Hseuh et al., EPAC 2002, Paris, France

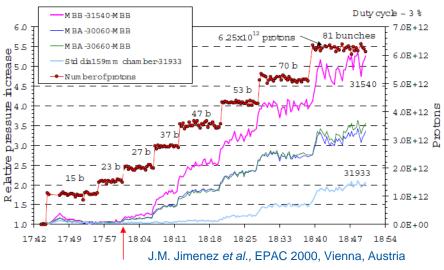


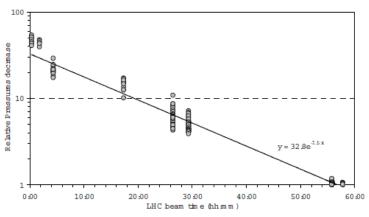
SPS

- Unbaked stainless steel vacuum chamber
- Pressure increase observed with LHC type beams
- Measurement of electron current on a pick up

- 60 h of beam conditioning
 - → Ok for LHC beam injection

7.7 10¹⁰ protons/bunch







Simple model

Synchronism condition:

$$\frac{2r_p}{\Delta v} \le t_{bb}$$

Speed increment due to the kick

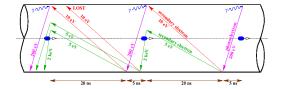
$$\Delta v = \frac{\Delta p}{m} = 2cr_e \frac{n_b}{r}$$

• Intensity threshold:

$$n_b = \frac{r_p^2}{r_e L_{bb}}$$

• Enough energy gain due to the kick to produce secondaries:

$$\Delta W = \frac{\Delta p^2}{2m} = 2 \frac{mc^2}{e} r_e^2 \left(\frac{n_b}{r}\right)^2$$



Schematic of electron-cloud build up in the LHC beam pipe.

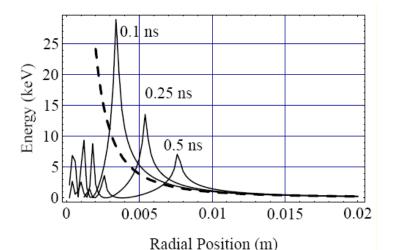


Figure: 1 Electron energy after the passage of a bunch in LHC versus the initial radial position for 0.1, 0.25 and 0.5 ns bunch length. The dotted curve is calculated for the stationary electron approximation.

O. Gröbner. PAC 97, Vancouver, Canada

Electrons in the vacuum chamber wall vicinity receive a kick of 190 eV, those in the beam vicinity receive 15 keV.



4.2 Photons from SR

Behaviour with critical energy

- SR irradiation at EPA
- Grazing incidence, 11 mrad
- The photoyield increases when increasing critical energy.
- Photon reflectivity slightly decreases when increasing critical energy
- PY*: photoelectrons per absorbed photons

		45 eV		194 eV	
Material	Status	R (%)	PY* (e/ph)	R (%)	PY* (e/ph)
A1	unbaked	-	0.11	-	0.32
Cu-smooth	unbaked	81	0.11	77	0.32
Cu- electrodeposited	unbaked	5	0.08	7	0.08
Cu-sawtooth	unbaked	8	0.03	7	0.04
TiZr	unbaked	20	0.06	17	0.08
TiZr	activated at 350°C	20	0.02	17	0.03

I.R. Collins et al. EPAC 1998, Stockholm, Sweden

NB: molecular desorption yields are linear in the range, 10 – 300 eV. So the photoelectron yield should be also proportional to critical

energy

 $PY * \sim E_c$

Photoelectrons for a LHC type beam screen

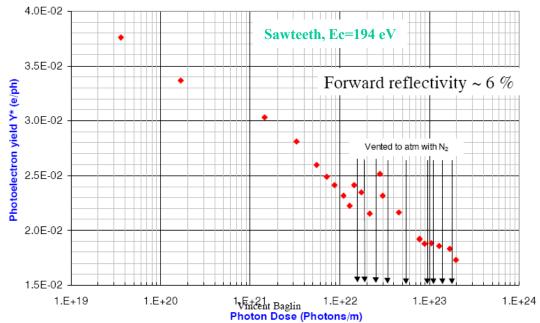
Complementary information

The Photoyield decrease with beam conditioning

~ 40 μm † ~ 500 μm

It varies from 1 to 4 % under perpendicular incidence

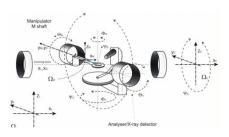




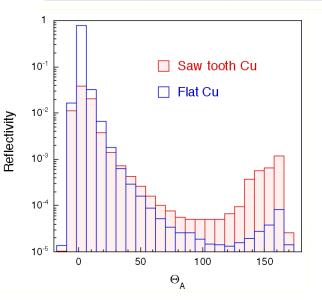
V. Baglin et al., Chamonix, 2001

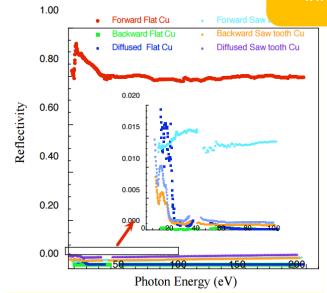
Complementary information

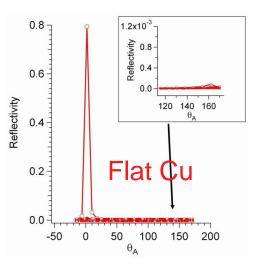
The saw tooth structure reduces the reflectivity

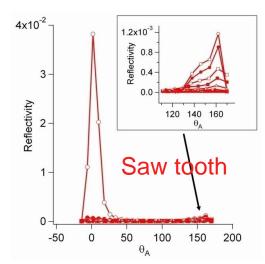


	Flat sample	Saw-tooth sample
Forward scattering	80 %	4 %
Back scattering	0 %	2 %
Diffused	2 %	4 %
Total	82 %	10 %









N. Mahne et al. App. Surf. Sci. 235, 221-226, (2004)



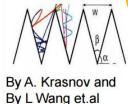
4.3 Electrons from the electron cloud

Geometrical effect

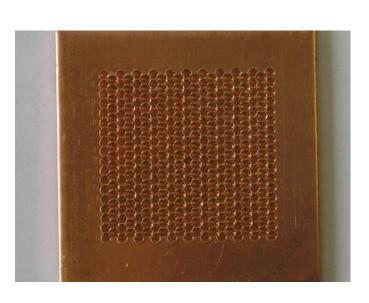
Complementary information

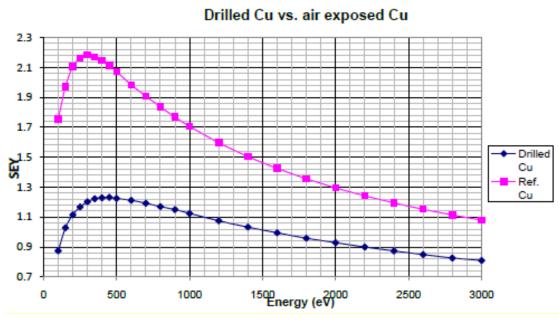
- After a coffee discussion, a drilled sampled by the VAC workshop (H. Kos)
- Ø ~1 mm , 92 holes/cm²

Original idea with groove only:



SEY max < 1.3 for Cu unbaked !!





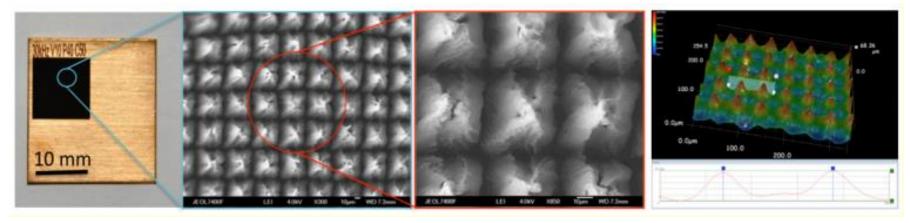
Measurement courtesy A. Kuzucan

A fancy effect or a real application?

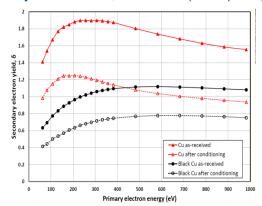


Complementary information

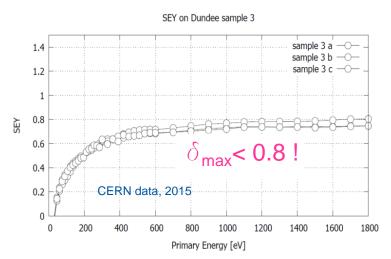
- Principle: laser treatment of a tube at atmospheric pressure
- Production of a micrometric structure



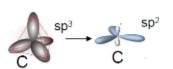
Appl. Phys. Lett. 101, 2319021 (2012). Physics Highlights – Physics Today (February 2013). Opt. Mater. Exp. 1,1425 (2011).



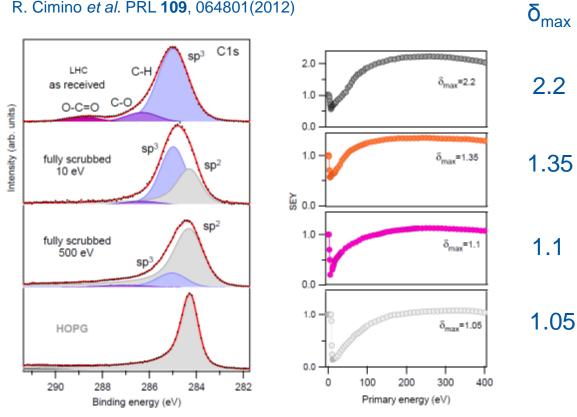
Applied Physics Letters 12/2014; 105(23): 231605



• Still under development by STFC and Dundee university, so it came too late for the LHC construction!



- Modification of C1s core level
- Conversion $sp^3 => sp^2$
- High energy electrons increase the number of graphitic like C-C bounds

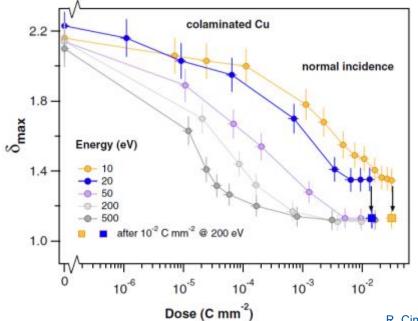


HOPG: highly oriented pyrolity graphite

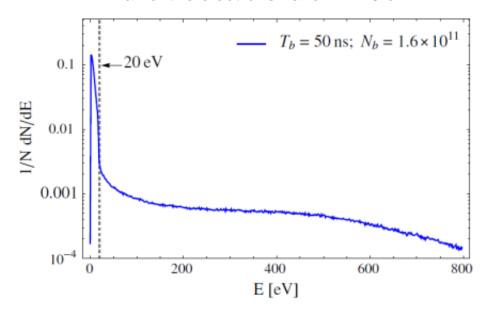
Graphitization of the carbon contamination layer under electron irradiation



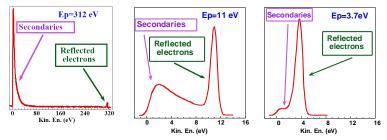
• At 300 K, the scrubbing efficiency of low energy electron is less than high energy electrons



- Electron energy distribution at the LHC vacuum chamber wall
- ~ half of the electrons have E < 20 eV



R. Cimino et al. PRL 109, 064801(2012)



R. Cimino, I.R. Collins, App. Surf. Sci. 235, 231-235, (2004)

Knowing the energy distribution of electrons is of paramount importance

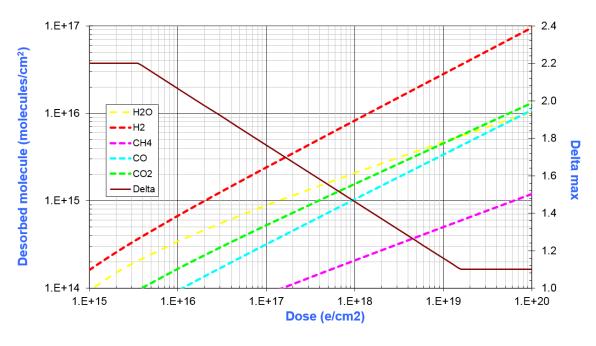


Complementary information

Electron scrubbing

- After a dose of ~ 5 10¹⁸ e/cm² i.e. 8 mC/mm², the maximum of SEY equals ~ 1.3
- The scrubbing process desorbs several monolayers of gas from the surface
- Potential impact on:
 - frequency of NEG activation
 - increase of SEY due to gas condensation

Unbaked Cu - ESD - 300 eV



	H ₂	CH ₄	H ₂ O	CO	CO ₂
Q x 10 ¹⁵	19	0.4	4	2	3

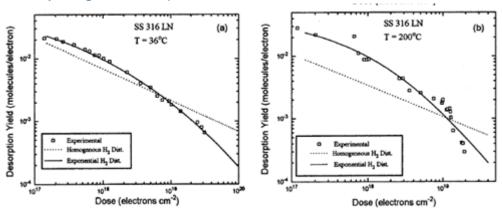
→ several monolayer of gas are desorbed when a surface is conditioned



Electron desorption studies at different temperature

Complementary information

Hydrogen desorption



 H₂ electron desorption can be explained by a diffusion model with a non-uniform concentration i.e. H is produced by dissociation of hydroxydes under electron bombardement

However, the diffusion coefficients taken for RT and 200°C were the same

- J. Gómez-Goñi, A.G. Mathewson. J. Vac. Sci. Technol. A 15(6) (1997) 3093
- No obvious correlation between the surface composition determined by AES and desorption yields as a function of temperature: No changes in AES spectra vs 1 to 3 orders of magnitude decrease for the yields.
- The thickness of the oxide layer is more than 3 monolayers (AES scanning depth).

A porous surface oxide layer provide the reservoir of gas

